## What is claimed is:

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1. A method of detecting the alignment of two layers in an integrated circuit comprising multiple stacked layers of material, one underlying layer having a first alignment mark and one overlying layer having a second alignment mark, the method comprising:

detecting the first alignment mark and a reference alignment mark using a first alignment tool and forming thereof a first image;

detecting the second alignment mark and the reference alignment mark using a second alignment tool and forming thereof a second image;

forming a composite image from the first and second image by aligning the reference mark in the first and second image.

- 2. The method of claim 1 further comprising scanning the integrated circuit relative to the first and second alignment tools.
- 3. The method of claim 1 wherein the step of detecting the first alignment mark comprises observing the integrated circuit with a wavefront sensing tool.
- 4. The method of claim 1 wherein the step of detecting the second alignment mark comprises observing the integrated circuit the mark with a microscope.
  - 5. The method of claim 1 wherein the reference mark comprises the first alignment mark.
- 25 6. The method of claim 1 wherein the step of detecting the first alignment mark further comprising claiminating the integrated circuit with a light source and magnifying light reflected from the integrated circuit.

- 7. An alignment detection apparatus comprising:
- a stage having a surface for receiving thereon a semiconductor wafer;
- a light source directed to illuminate a wafer when placed upon said stage with a light having a predetermined wavelength;
- a beam splitter located to intercept light from said light source reflected off a wafer placed upon said stage and to split said reflected light into a first light path and a second light path;
  - an optical tool in the first light path;
  - a wavefront sensing tool in the second light path; and
- a computer coupled to the optical tool and the wavefront sensing tool and receiving there from alignment detection data and outputting an alignment image.
  - 8. The alignment detection apparatus of claim 7 further comprising a device for moving a semiconductor wafer placed on the stage in relation to the optical tool and wavefront sensing tool.
- 15 9. The alignment detection apparatus of claim 7 wherein the optical tool is a microscope.
  - 10. The alignment detection apparatus of claim 7 wherein the wavefront sensing tool is a Shack-Hartmann detector.
- 11. The alignment detection apparatus or claim 7 wherein the computer is integrated within either the optical tool or the wavefront sensing tool.
  - 12. The alignment detection apparatus of claim 7 wherein the alignment image is an image of alignment teatures, at least one of which is on the surface of a wafer placed on the stage.
- 13. The alignment detection apparatus of claim 12 in which the alignment features comprises a feature formed of photoresist on the surface of the wafer.
  - 14. The alignment setection apparatus of claim 13 wherein the alignment features have a height of less than one fourth the wavelength of the light source.
  - 15. The alignment detection apparatus of draim 12 in which the alignment features comprise a feature formed on a layer beneath the surface of the wafer.

16. A method for measuring the overlay alignment of at least two layers of a semiconductor device using a wavefront sensing tool comprising:

generating a reference signal by observing a flat reference surface with the wavefront sensing tool and storing the resulting signal;

5 aligning at least a portion of the semiconductor wafer containing a first and second alignment mark with the wavefront sensing tool;

illuminating the portion of the wafer and detecting a wavefront of light reflected from the portion of the wafer and from the first and second alignment marks;

magnifying the reflected wavefront of light:

10 generating a wavefront slope signal by observing the magnified reflected wavefront of light with the wavefront sensing tool;

determining the location of the first and second alignment marks be comparing the wavefront slope signal with the reference signal; and

calculating a distance between the first and second alignment marks based upon the results of the step of determining the location of the first and second alignment marks.

- 17. The method of claim 16 further comprising generating an image of the first and second alignment marks.
- 18. The method or claim 16 further comprising observing the reflected wavelength of light with an optical tool and determining the location of a third alignment and creating an image of the third alignment mark.
  - 19. The method of claim 18 further comprising creating a composite image of the image of the first and second alignment marks and the image of the third alignment mark.
- 25. The method of claim 19 wherein the composite image is created by aligning a common feature desected by comit the wavefront sensing tool and the optical tool.
  - 21. The method of claim of where the unit alignment mark is in a layer underlying the first and second alignment marks.
- 30 22. The method of claim 18 wherein the wavefront of light has a wavelength and the first and second ai gnment marks have a height that is less than one fourth of said wavelength

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